Product data sheet

## 1. Product profile

### 1.1 General description

High-voltage switching diodes, encapsulated in a SOT23 small Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

| Type number | Package |       | Configuration |
|-------------|---------|-------|---------------|
|             | NXP     | JEITA |               |
| BAS101      | SOT23   | -     | single        |
| BAS101S     | SOT23   | -     | dual series   |

### 1.2 Features

- High switching speed:  $t_{rr} \le 50$  ns
- Low leakage current
- Repetitive peak reverse voltage: V<sub>RRM</sub> ≤ 300 V
- Low capacitance: C<sub>d</sub> ≤ 2 pF
- Reverse voltage: V<sub>R</sub> ≤ 300 V
- Small SMD plastic package

### 1.3 Applications

- High-speed switching
- High-voltage switching

- Voltage clamping
- Reverse polarity protection

### 1.4 Quick reference data

Table 2. Quick reference data

| Symbol          | Parameter             | Conditions              | Min          | Тур | Max | Unit |
|-----------------|-----------------------|-------------------------|--------------|-----|-----|------|
| Per diode       |                       |                         |              |     |     |      |
| IF              | forward current       |                         | -            | -   | 200 | mA   |
| I <sub>R</sub>  | reverse current       | $V_{R} = 250 \text{ V}$ | -            | -   | 150 | nA   |
| V <sub>R</sub>  | reverse voltage       |                         | -            | -   | 300 | V    |
| t <sub>rr</sub> | reverse recovery time |                         | <u>[1]</u> _ | -   | 50  | ns   |

<sup>[1]</sup> When switched from  $I_F = 30$  mA to  $I_R = 30$  mA;  $R_L = 100 \Omega$ ; measured at  $I_R = 3$  mA.





High-voltage switching diodes

#### **Pinning information** 2.

| Description                           | Simplified outline                      | Symbol  |
|---------------------------------------|---|---|
|                                       |   |   |
|                                       |   |   |
| anode                                 |   | •   |
| not connected                         | 3                                       | 3   |
| cathode                               | 1 2                                     | 1 2<br>006aaa764                                      |
|                                       |   |   |
| anode (diode 1)                       |   |   |
| cathode (diode 2)                     | 3                                       | 3   |
| cathode (diode 1),<br>anode (diode 2) | 1 2                                     |   |
|                                       | cathode (diode 2)<br>cathode (diode 1), | cathode (diode 2)  cathode (diode 1), anode (diode 2) |

#### **Ordering information** 3.

Table 4. **Ordering information** 

| Type number | Package |  |         |  |
|-------------|---------|--|---------|--|
|             | Name    | Description                              | Version |  |
| BAS101      | -       | plastic surface-mounted package; 3 leads | SOT23   |  |
| BAS101S     |         |  |         |  |

#### **Marking** 4.

Table 5. **Marking codes** 

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| BAS101      | *HQ                         |
| BAS101S     | *HR                         |

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

High-voltage switching diodes

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

|                  |                                     | <del>-</del> -  | =            |      |      |
|------------------|-------------------------------------|---|--------------|------|------|
| Symbol           | Parameter                           | Conditions  | Min          | Max  | Unit |
| Per diode        |                                     |   |              |      |      |
| $V_{RRM}$        | repetitive peak reverse             |   | -            | 300  | V    |
|                  | voltage                             | series connection   | -            | 600  | V    |
| $V_R$            | reverse voltage                     |   | -            | 300  | V    |
|                  |                                     | series connection   | -            | 600  | V    |
| I <sub>F</sub>   | forward current                     |   | -            | 200  | mA   |
|                  |                                     | series connection   | -            | 100  | mA   |
| I <sub>FRM</sub> | repetitive peak forward current     | $\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$ | -            | 1    | Α    |
| I <sub>FSM</sub> | non-repetitive peak forward current | square wave; $t_p \le 1 \mu s$  | <u>[1]</u> _ | 9    | А    |
| Per device       |                                     |   |              |      |      |
| P <sub>tot</sub> | total power dissipation             | $T_{amb} \le 25  ^{\circ}C$   | [2] _        | 250  | mW   |
| Tj               | junction temperature                |   | -            | 150  | °C   |
| T <sub>amb</sub> | ambient temperature                 |   | -65          | +150 | °C   |
| T <sub>stg</sub> | storage temperature                 |   | -65          | +150 | °C   |
|                  |                                     |   |              |      |      |

<sup>[1]</sup>  $T_j = 25$  °C prior to surge

## 6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol               | Parameter                                   | Conditions  | Min          | Тур | Max | Unit |
|----------------------|---|-------------|--------------|-----|-----|------|
| Per device           |   |             |              |     |     |      |
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient | in free air | <u>[1]</u> - | -   | 500 | K/W  |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

High-voltage switching diodes

## 7. Characteristics

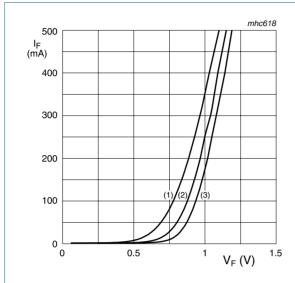
Table 8. Characteristics

 $T_{amb} = 25 \, ^{\circ}\text{C}$  unless otherwise specified.

| · aiiib = 0     | e ameso sano meso spess |   |              |     |     |      |
|-----------------|-------------------------|---|--------------|-----|-----|------|
| Symbol          | Parameter               | Conditions                                      | Min          | Тур | Max | Unit |
| Per diod        | е                       |   |              |     |     |      |
| V <sub>F</sub>  | forward voltage         | I <sub>F</sub> = 100 mA                         | <u>[1]</u> - | -   | 1.1 | V    |
| I <sub>R</sub>  | reverse current         | V <sub>R</sub> = 250 V                          | -            | -   | 150 | nA   |
|                 |                         | V <sub>R</sub> = 250 V; T <sub>j</sub> = 150 °C | -            | -   | 100 | μΑ   |
| C <sub>d</sub>  | diode capacitance       | $V_R = 0 V$ ; $f = 1 MHz$                       | -            | -   | 2   | pF   |
| t <sub>rr</sub> | reverse recovery time   |   | [2] _        | -   | 50  | ns   |

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ .

<sup>[2]</sup> When switched from  $I_F = 30$  mA to  $I_R = 30$  mA;  $R_L = 100 \Omega$ ; measured at  $I_R = 3$  mA.



- (1) T<sub>amb</sub> = 150 °C
- (2)  $T_{amb} = 75 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values

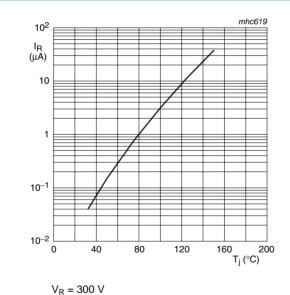
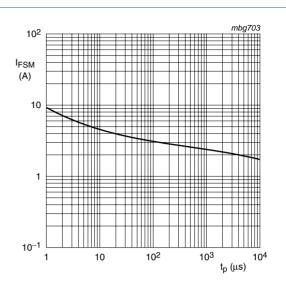


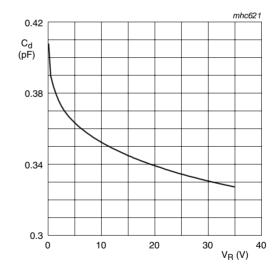
Fig 3. Reverse current as a function of junction temperature; typical values



Based on square wave currents

T<sub>i</sub> = 25 °C; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values

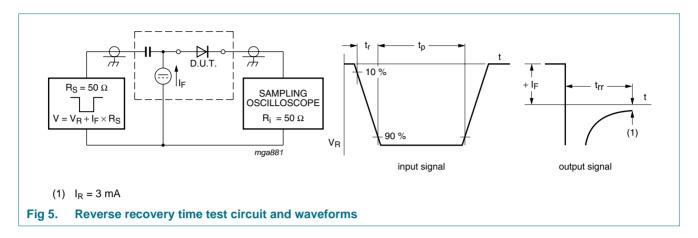


 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$ 

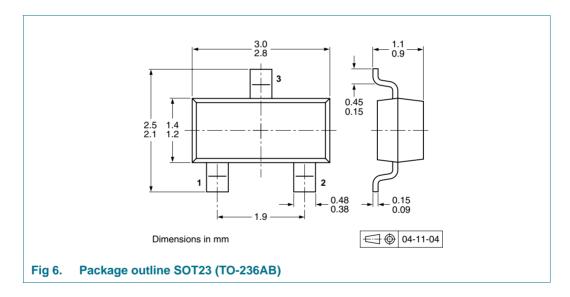
Fig 4. Diode capacitance as a function of reverse voltage; typical values

High-voltage switching diodes

## 8. Test information



## 9. Package outline



## 10. Packing information

Table 9. Packing methods

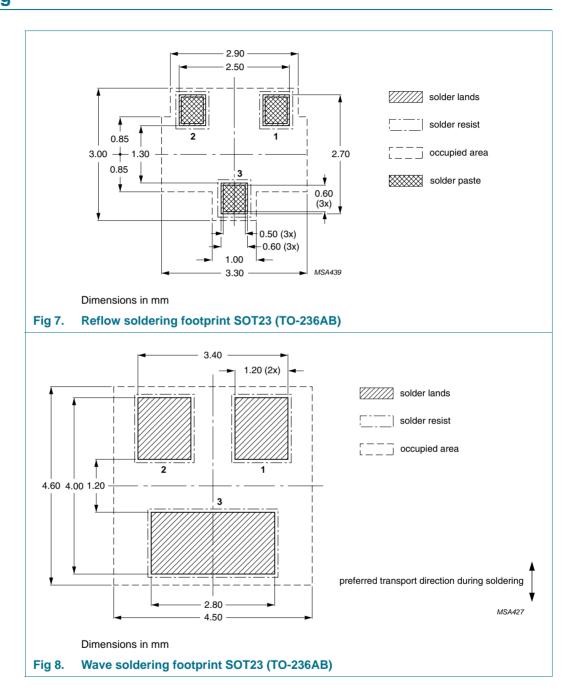
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                          | Packing quantity |       |
|-------------|---------|--------------------------------------|------------------|-------|
|             |         |                                      | 3000             | 10000 |
| BAS101      | SOT23   | SOT23 4 mm pitch, 8 mm tape and reel | -215 -235        | -235  |
| BAS101S     |         |                                      |                  |       |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 15.

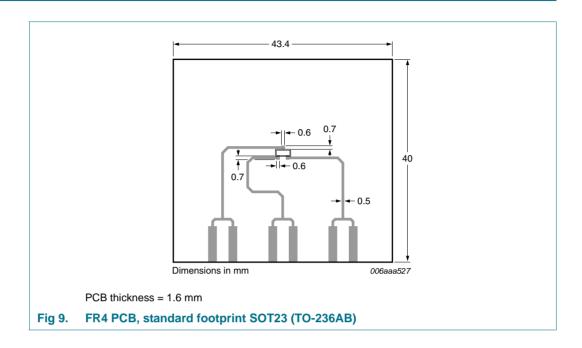
High-voltage switching diodes

## 11. Soldering



High-voltage switching diodes

## 12. Mounting



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**High-voltage switching diodes** 

## 13. Revision history

### Table 10. Revision history

| Document ID      | Release date              | Data sheet status  | Change notice | Supersedes       |  |
|------------------|---------------------------|--|---------------|------------------|--|
| BAS101_BAS101S_2 | 20091214                  | Product data sheet   | -             | BAS101_BAS101S_1 |  |
| Modifications:   | including nev<br>content. | <ul> <li>This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technica content.</li> <li>Table 3 "Pinning": updated</li> </ul> |               |                  |  |
| BAS101_BAS101S_1 | 20060908                  | Product data sheet   | -             | -                |  |

High-voltage switching diodes

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### 14.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# **BAS101; BAS101S**

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